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# PDTA143/114/124/144EQA Series 50 V, 100 mA PNP resistor-equipped transistors Rev. 1 — 18 December 2015 Pro

**Product data sheet** 

#### **Product profile** 1.

#### **1.1 General description**

100 mA PNP Resistor-Equipped Transistor (RET) family in a leadless ultra small DFN1010D-3 (SOT1215) Surface-Mounted Device (SMD) plastic package with visible and solderable side pads.

#### Table 1. **Product overview**

Type number	R1	R2	Package NXP	NPN complement
PDTA143EQA	4.7 kΩ	4.7 kΩ	DFN1010D-3	PDTC143EQA
PDTA114EQA	10 kΩ	10 kΩ	(SOT1215)	PDTC114EQA
PDTA124EQA	22 kΩ	22 kΩ	-	PDTC124EQA
PDTA144EQA	47 kΩ	47 kΩ	-	PDTC144EQA

### 1.2 Features and benefits

- 100 mA output current capability
- built-in bias resistors
- simplifies circuit design
- reduces component count

# **1.3 Applications**

- digital applications
- cost saving alternative for BC847/BC857 series in digital applications

## 1.4 Quick reference data

#### Table 2. **Quick reference data**

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>CEO</sub>	collector-emitter voltage	open base	-	-	-50	V
I <sub>O</sub>	output current		-	-	-100	mA



- reduced pick and place costs
- Iow package height of 0.37 mm
- AEC-Q101 qualified
- suitable for Automatic Optical Inspection (AOI) of solder joint

controlling IC inputs

switching loads

50 V, 100 mA PNP resistor-equipped transistors

# 2. Pinning information

Table 3.	Pinning			
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	1	input (base)		
2	GND	GND (emitter)		
3	0	output (collector)		
4	0	output (collector)	2   4   3     Transparent top view	GND

# 3. Ordering information

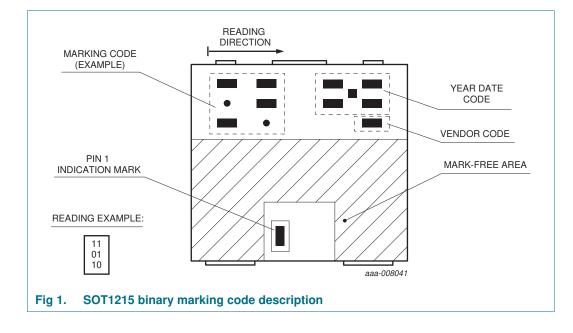
Table 4. Ordering information						
Type number	Package					
	Name	Description	Version			
PDTA143EQA	DFN1010D-3	plastic thermal enhanced ultra thin small outline	SOT1215			
PDTA114EQA		package; no leads; 3 terminals; body: $1.1 \times 1.0 \times 0.37$ mm				
PDTA124EQA						
PDTA144EQA						

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# 4. Marking

Table 5. Marking codes	
Type number	Marking code
PDTA143EQA	10 10 11
PDTA114EQA	11 01 11
PDTA124EQA	10 11 10
PDTA144EQA	10 01 11

## 4.1 Binary marking code description



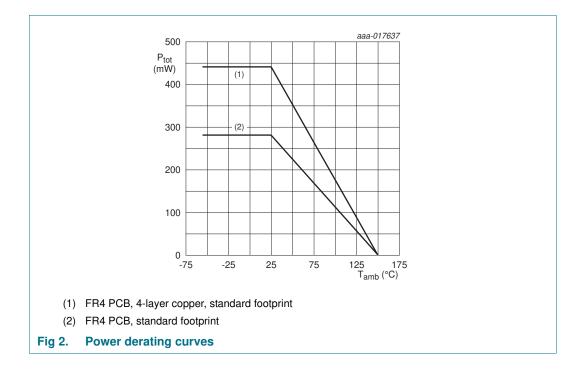
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# 5. Limiting values

<b>Table 6.</b> In accordar	Limiting values ace with the Absolute Maximur	m Rating System (IE0	C 60134).		
Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CBO</sub>	collector-base voltage	open emitter	-	-50	V
V <sub>CEO</sub>	collector-emitter voltage	open base	-	-50	V
V <sub>EBO</sub>	emitter-base voltage	open collector	-	-10	V
VI	input voltage		i		
	PDTA143EQA		-30	+10	V
	PDTA114EQA		-40	+10	V
	PDTA124EQA		-40	+10	V
	PDTA144EQA		-40	+10	V
lo	output current		-	-100	mA
P <sub>tot</sub>	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$	[1] -	280	mW
			[2] _	440	mW
Tj	junction temperature		-	150	°C
T <sub>amb</sub>	ambient temperature		-55	+150	°C
T <sub>stg</sub>	storage temperature		-65	+150	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, 4-layer copper, tin-plated and standard footprint.



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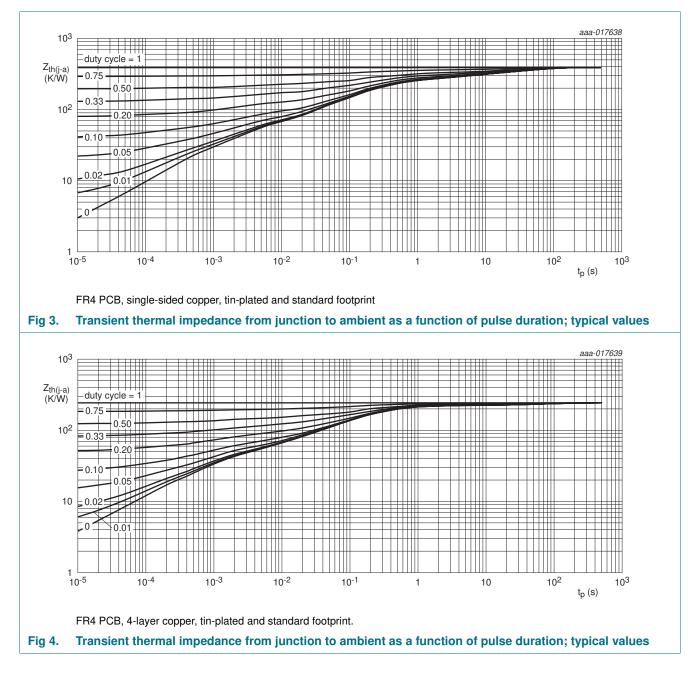
# 6. Thermal characteristics

		O an diti an a		N.4:	<b>T</b>		11
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R <sub>th(j-a)</sub>	thermal resistance from junction	in free air	<u>[1]</u>	-	-	446	K/W
to ambient			[2]	-	-	284	K/W

#### Table 7. Thermal characteristics

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, 4-layer copper, tin-plated and standard footprint.



50 V, 100 mA PNP resistor-equipped transistors

# 7. Characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
СВО	collector-base cut-off current	$V_{CB} = -50 \text{ V}; I_E = 0 \text{ A}$		-	-	-100	nA
I <sub>CEO</sub>	collector-emitter cut	$V_{CE} = -30; I_B = 0 A;$		-	-	-1	μA
	off current	V <sub>CE</sub> = -30; I <sub>B</sub> = 0 A; T <sub>j</sub> = 150 °C		-	-	-5	μA
EBO	emitter-base cut-off cu	rrent					
	PDTA143EQA	$V_{EB} = -5 V; I_C = 0 A$ -		-	-	-900	μA
	PDTA114EQA		-		-	-400	μA
	PDTA124EQA	-		-	-	-180	μA
	PDTA144EQA	-		-	-	-90	μA
٦ <sub>FE</sub>	DC current gain						
	PDTA143EQA	V <sub>CE</sub> = -5 V; I <sub>C</sub> = -10 mA		30	-	-	
	PDTA114EQA	$V_{CE} = -5 \text{ V}; \text{ I}_{C} = -5 \text{ mA}$		30	-	-	
	PDTA124EQA	$V_{CE} = -5 \text{ V}; I_{C} = -5 \text{ mA}$		60	-	-	-
	PDTA144EQA	$V_{CE} = -5 \text{ V}; I_{C} = -5 \text{ mA}$		80	-	-	-
V <sub>CEsat</sub>	collector-emitter saturation voltage	$I_{\rm C} = -10 \text{ mA}; I_{\rm B} = -0.5 \text{ mA}$		-	-	-150	mV
V <sub>I(off)</sub>	off-state input voltage						
	PDTA143EQA	$V_{CE} = -5 \text{ V}; \text{ I}_{C} = -100 \mu\text{A}$		-	-1.1	-0.5	V
	PDTA114EQA	-		-	-1.1	-0.8	V
	PDTA124EQA				-1.1	-0.8	V
	PDTA144EQA		-	-1.2	-0.8	V	
V <sub>I(on)</sub>	on-state input voltage						
	PDTA143EQA	V <sub>CE</sub> = -0.3 V; I <sub>C</sub> = -20 mA		-2.5	-1.9	-	V
	PDTA114EQA	V <sub>CE</sub> = -0.3 V; I <sub>C</sub> = -10 mA		-2.5	-1.8	-	V
	PDTA124EQA	$V_{CE} = -0.3 \text{ V}; I_{C} = -5 \text{ mA}$		-2.5	-1.7	-	V
	PDTA144EQA	$V_{CE} = -0.3 \text{ V}; I_C = -2 \text{ mA}$		-3	-1.6	-	V
R1	bias resistor 1 (input)		[1]				
	PDTA143EQA			3.3	4.7	6.1	kΩ
	PDTA114EQA			7	10	13	kΩ
	PDTA124EQA			15.4	22	28.6	kΩ
	PDTA144EQA			33	47	61	kΩ
R2/R1	bias resistor ratio		[1]	0.8	1	1.2	
C <sub>c</sub>	collector capacitance	$V_{CB} = -10 \text{ V}; I_E = i_e = 0 \text{ A}; f = 1 \text{ MHz}$		-	-	3	pF
fT	transition frequency	V <sub>CE</sub> = -5 V; I <sub>C</sub> = -10 mA; f = 100 MHz	[2]	-	180	-	MHz

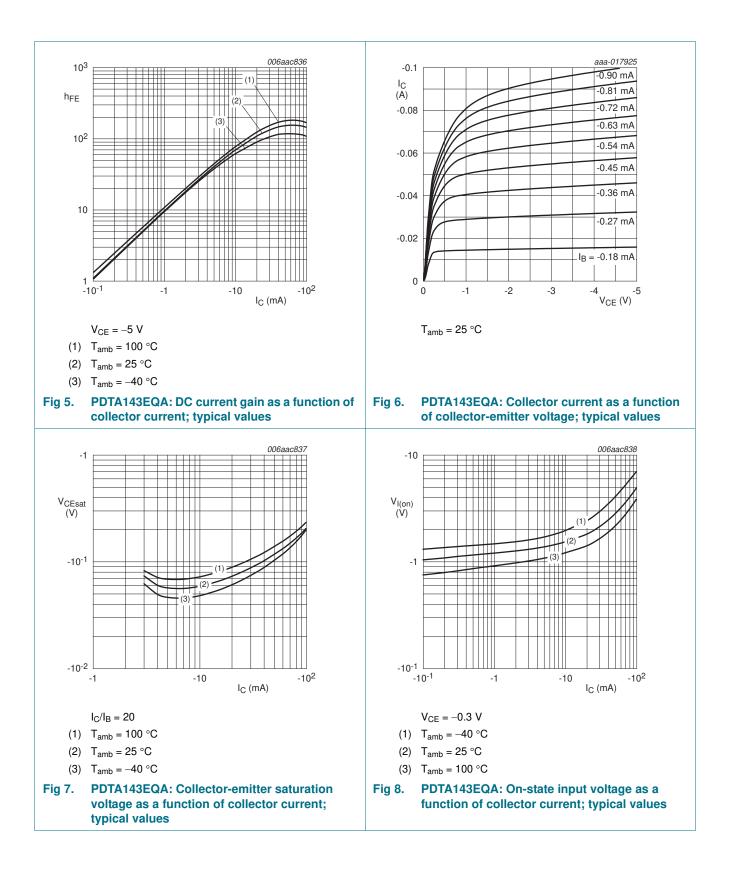
[1] See section test information for resistor calculation and test conditions.

[2] Characteristics of built-in transistor.

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Product data sheet

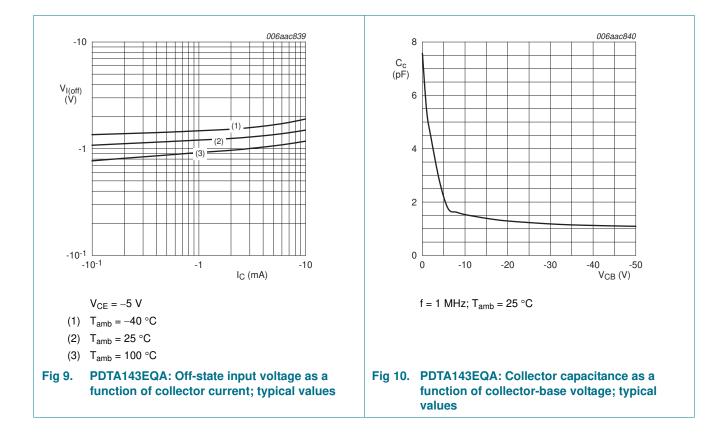
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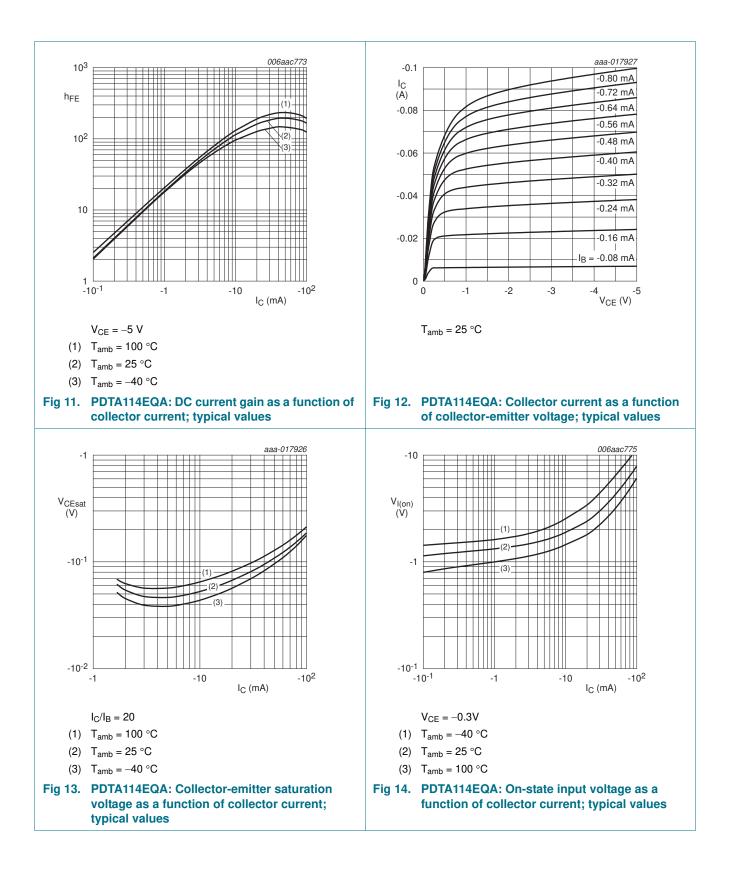


# PDTA143/114/124/144EQA series

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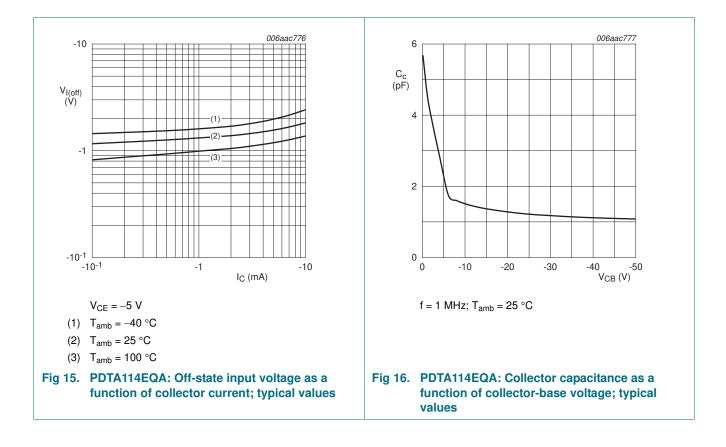


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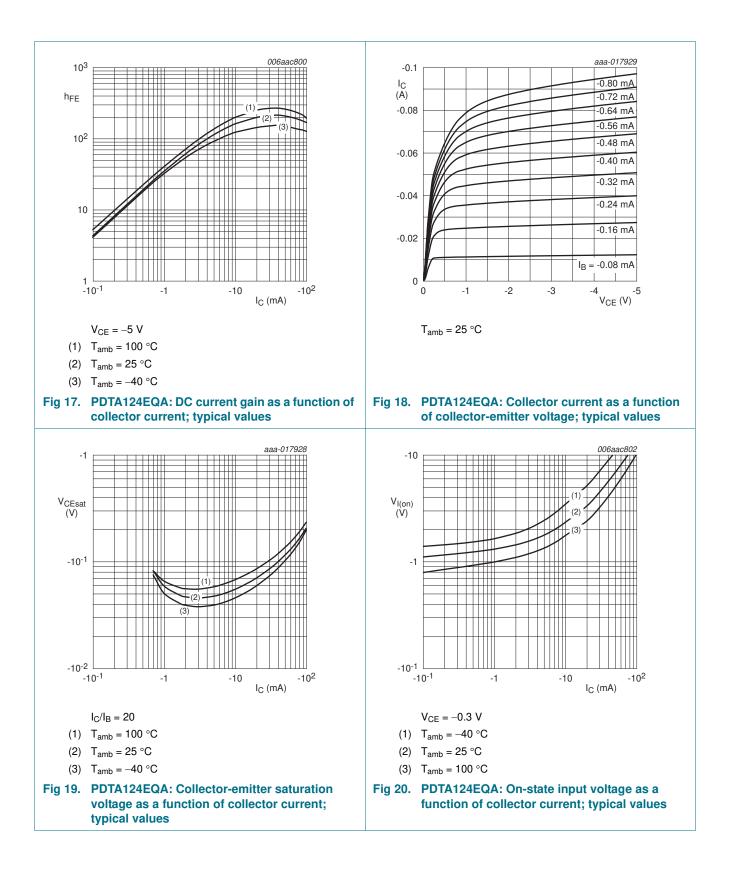
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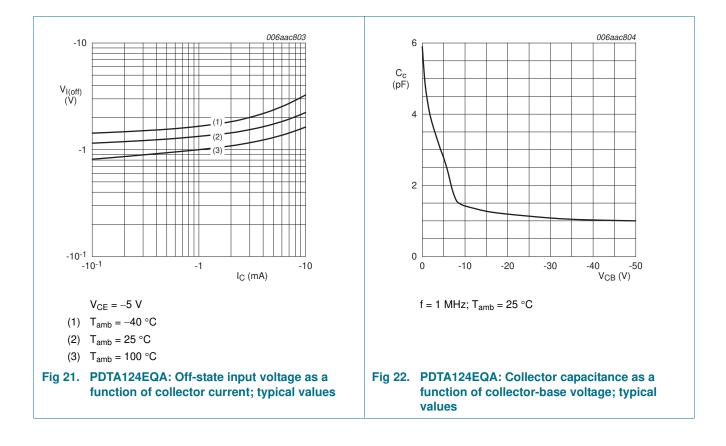
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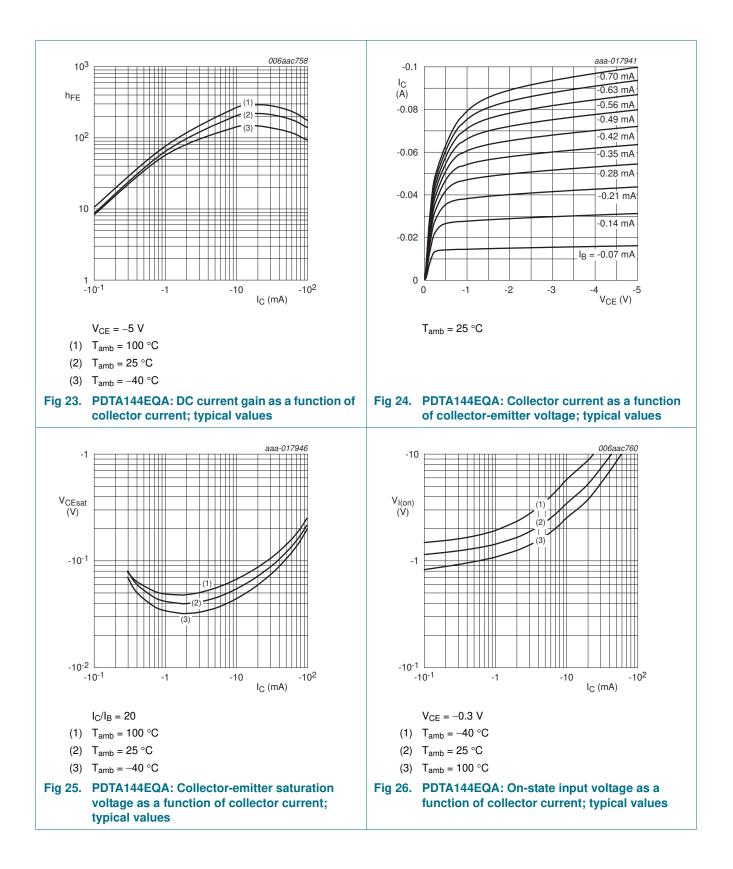


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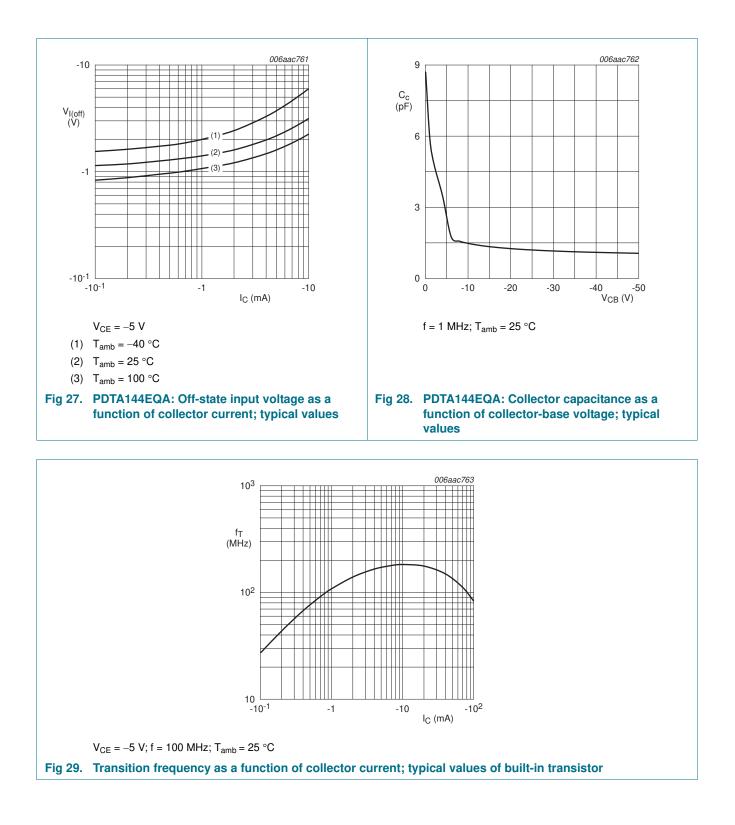
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# PDTA143/114/124/144EQA series

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# 8. Test information

#### 8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

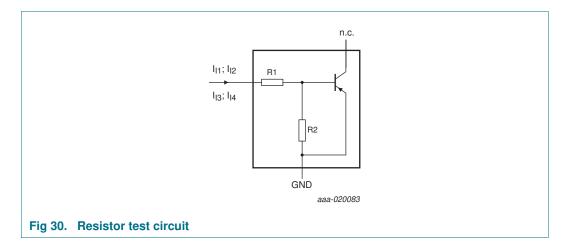
#### 8.2 Resistor calculation

• Calculation of bias resistor 1 (R1):

$$R1 = \frac{V(I_{12}) - V(I_{11})}{I_{12} - I_{11}}$$

• Calculation of bias resistor ratio (R2/R1):

$$\frac{R2}{R1} = \frac{V(I_{I4}) - V(I_{I3})}{R1 \cdot (I_{I4} - I_{13})} - 1$$



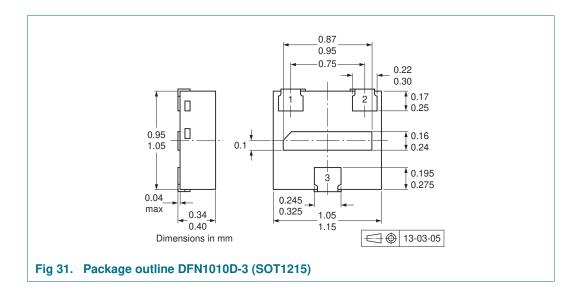
#### 8.3 Resistor test conditions

#### Table 9. Resistor test conditions

Type number	R1	R2	Test conditions				
	(kΩ)	(kΩ)	I <sub>11</sub>	I <sub>12</sub>	I <sub>13</sub>	I <sub>14</sub>	
PDTA143EQA	4.7	4.7	–600 μA	–700 μA	600 μA	700 μ <b>Α</b>	
PDTA114EQA	10	10	–350 μA	–450 μA	350 μA	450 μA	
PDTA124EQA	22	22	–150 μA	–230 μA	150 μA	230 μA	
PDTA144EQA	47	47	–55 μA	–105 μA	55 μΑ	105 μA	

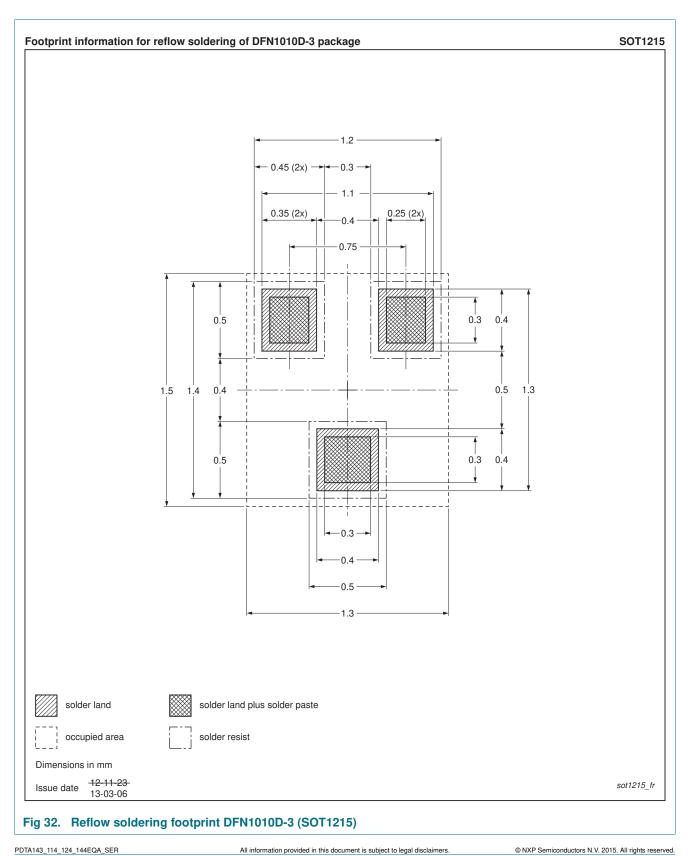
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# 9. Package outline



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# 10. Soldering



**Product data sheet** 

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# **11. Revision history**

#### Table 10. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
PDTA143/114/124/144EQA_	20151218	Product data sheet	-	-
SER v.1				

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# 12. Legal information

#### 12.1 Data sheet status

Document status[1][2]	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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#### 50 V, 100 mA PNP resistor-equipped transistors

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50 V, 100 mA PNP resistor-equipped transistors

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Date of release: 18 December 2015 Document identifier: PDTA143\_114\_124\_144EQA\_SER